

Formation of large area Al contacts on 6H- and 4H-SiC substrates

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Thermopower measurements in 4H-SiC and theoretical calculations considering the phonon drag effect

Grivickas, V.; Stölzer, M.; **Velme, Enn; Udal, Andres**; Grivickas, P.; Syväjärvi, M.; Yakimova, R.; Bikbajevs, V. Silicon Carbide and Related Materials : ECSCRM2000 : proceedings of the 3rd European Conference on Silicon Carbide and Related Materials : Kloster Banz, Germany, September 2000 2001 / p. 491-494 : ill